

ISSI is now sampling a 32Mb High Speed Low Power Asynchronous SRAM, the latest addition to our SRAM portfolio. This innovative design reinforces ISSI's longterm commitment to SRAMs with the highest quality and performance.

32Mb SRAM provides an access time of 10ns at Automotive, A3 temperature range (-40°C to +125°C).

## ► Applications

- Automotive
- Industrial/Medical
- Telecom/Networking

## 32Mb High Speed Low Power SRAM IS61/64WV204816BLL



## Key Features

	IS61WV204816BLL (I)	IS64WV204816BLL (A3)	Comments
Temperature Support	Industrial (-40°C to +85°C)	Automotive (-40°C to +125°C)	
Technology	40nm	40nm	
Supply Voltage	2.4V ~ 3.6V	2.4V ~ 3.6V	
Operating Current (Max)	95mA	140mA	Typical value 60 mA
Standby Current (Typ)	4mA	4mA	
Packaging	TSOP-I (48 pins) BGA (48 balls)	TSOP-I (48 pins) BGA (48 balls)	Pin compatible with 16Mb Async. SRAM
Speed	10ns	10ns	
Copper Leadframe	Yes	Yes	
Lead-free PKG	Yes	Yes	RoHS Compliant
Availability	Sampling Now	Sampling Now	

## **Cross Reference Guide**

Competitor Part No.	ISSI Part No.	Description	
CY7C107DV33-12BAXI	IS61WV204816BLL-12BLI	32Mb Asynchronous SRAM, 3.3V, 12ns, 48FBGA, I-Temp	